NSN 5961-01-606-5507

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-606-5507
Inclosure Material:
Glass
Overall Length:
3.7 inches
Overall Height:
1.18 inches
Overall Width:
1.34 inches
Function For Which Designed:
Rectifier
End Application:
Power supply
Mounting Facility Quantity:
2
Mounting Method:
Unthreaded hole
Features Provided:
W/heat sink
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1800.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
150.0 amperes average forward current averaged over a full 60-hz cycle
Power Rating Per Characteristic:
12.0 watts peak gate power dissipation
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Product Name:
Dual scr isolated module
Terminal Type And Quantity:
3 threaded hole
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0